



8. (Currently Amended) ~~A ceramic electronic component according to claim 7,~~  
ceramic electronic component comprising:

\_\_\_\_\_ a ceramic substrate;

\_\_\_\_\_ a conductive layer which is formed in at least one of the inside and outside of  
the ceramic substrate and comprises a metal particle and a metal oxide particle,

\_\_\_\_\_ wherein said metal oxide particle which has an average particle size of 5 to 60  
nm and a melting point of 1500°C or higher, and

\_\_\_\_\_ wherein a content of the metal oxide particle is 0.1 to 10.0 wt% based on the  
amount of the metal particle; and

\_\_\_\_\_ which comprises a capacitor formed by including the ceramic substrate and the  
conductive layer, wherein, in the conductive layer, the metal particle is at least one kind  
selected from nickel and nickel alloys, and the metal oxide particle is an oxide compound  
comprising at least one kind of metals selected from magnesium, aluminum, titanium and  
zirconium.

9. (Currently Amended) ~~A ceramic electronic component according to claim 7,~~  
A ceramic electronic component comprising:

\_\_\_\_\_ a ceramic substrate;

\_\_\_\_\_ a conductive layer which is formed in at least one of the inside and outside of  
the ceramic substrate and comprises a metal particle and a metal oxide particle,

\_\_\_\_\_ wherein said metal oxide particle which has an average particle size of 5 to 60  
nm and a melting point of 1500°C or higher, and

\_\_\_\_\_ wherein a content of the metal oxide particle is 0.1 to 10.0 wt% based on the  
amount of the metal particle; and

\_\_\_\_\_ which comprises an insulator formed by including the ceramic substrate and  
the conductive layer, wherein, in the conductive layer, the metal particle is at least one kind

selected from silver and silver alloys, and the metal oxide particle is an oxide compound comprising at least one kind of metals selected from magnesium, aluminum, titanium and zirconium.

10. (New) A conductive composition which is used for a conductor of an electronic component, comprising a metal particle and a metal oxide particle,
- wherein said metal oxide particle which has an average particle size of 5 to 60 nm and a melting point of 1500°C or higher, and
- wherein a content of the metal oxide particle is 0.1 to 10.0 wt% based on the amount of the metal particle, and
- wherein the metal oxide particle is an oxide compound comprising at least one kind of metals selected from magnesium, aluminum, titanium, and zirconium.

11. (New) A conductive composition which is used for a conductor of an electronic component comprising a metal particle and a metal oxide particle which has a BET value of 20 to 200 m<sup>2</sup>/g and a melting point of 1500°C or higher,
- wherein a content of the metal oxide particle is 0.1 to 10.0 wt% based on the amount of the metal particle, and
- wherein the metal oxide particle is an oxide compound comprising at least one kind of metals selected from magnesium, aluminum, titanium, and zirconium.